**Panasonic** 

# 2SD2460

### Silicon NPN epitaxial planer type

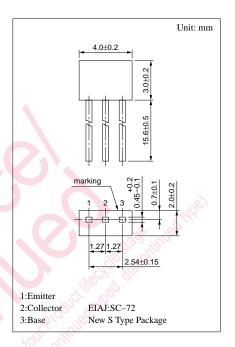
For low-frequency output amplification

#### Features

- High foward current transfer ratio h<sub>FE</sub>.
- ullet Low collector to emitter saturation voltage  $V_{\text{CE(sat)}}$ .
- Allowing supply with the radial taping.

#### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V <sub>CBO</sub>	20	V	
Collector to emitter voltage	V <sub>CEO</sub>	20	V	
Emitter to base voltage	V <sub>EBO</sub>	15	V	
Peak collector current	$I_{CP}$	1.5	A	
Collector current	$I_{C}$	0.7	A	
Collector power dissipation	P <sub>C</sub>	300	mW	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	$T_{\rm stg}$	<b>−55 ~ +150</b>	°C	

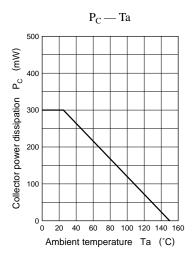


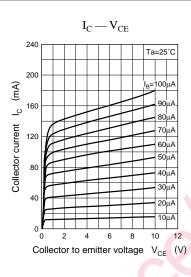
#### Electrical Characteristics (Ta=25°C)

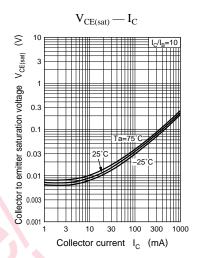
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 15V, I_E = 0$			1	μA
	$I_{CEO}$	$V_{CE} = 15V, I_{B} = 0$			10	μA
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$	20			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_C = 1$ mA, $I_B = 0$	20			V
Emitter to base voltage	V <sub>EBO</sub>	$I_E = 10 \mu A, I_C = 0$	15			V
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 10V, I_{C} = 150mA^{*}$	1000		2500	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 500 \text{mA}, I_B = 50 \text{mA}^*$		0.15	0.4	V
Transition frequency	$f_{T}$	$V_{CB} = 20V, I_E = -20mA, f = 200MHz$		55		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_E = 0, f = 1MHz$		10	15	pF

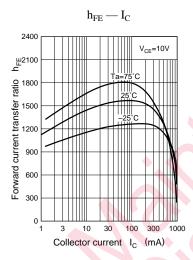
\* Pulse measurement

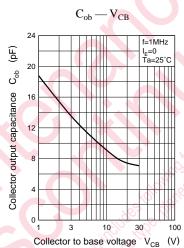
Transistor 2SD2460











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